

General Description

The MAX4729/MAX4730 single-pole/double-throw (SPDT) switches operate from a single supply ranging from +1.8V to +5.5V. These switches provide low 3.5Ω on-resistance (R_{ON}), as well as 0.45Ω R_{ON} flatness with a +2.7V supply. These devices typically consume only 1nA of supply current, making them ideal for use in lowpower, portable applications. The MAX4729/MAX4730 feature low-leakage currents over the extended temperature range, TTL/CMOS-compatible digital logic, and excellent AC characteristics.

The MAX4729/MAX4730 are available in small 6-pin SC70 and 6-pin µDFN packages. The MAX4729/ MAX4730 are offered in three pinout configurations to ease design. The MAX4729/MAX4730 are specified over the extended -40°C to +85°C temperature range.

Applications

Battery-Operated Equipment Audio and Video-Signal Routing Low-Voltage Data-Acquisition Systems Sample-and-Hold Circuits Communications Circuits Relay Replacement

Features

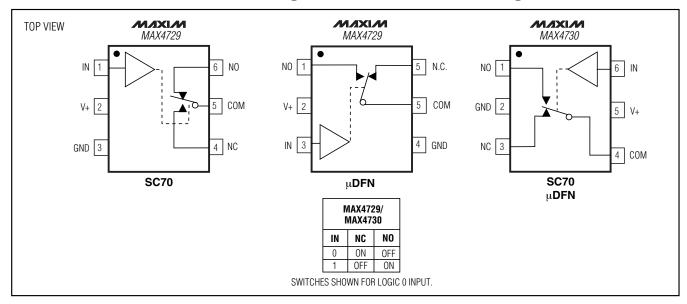
- ♦ Low 3.5Ω Ron (+2.7V Supply)
- ♦ 0.45Ω Ron Flatness (+2.7V Supply)
- ♦ 0.05Ω Ron Match Between Channels (+2.7V Supply)
- ◆ Tiny SC70 and µDFN Packages
- ◆ -3dB Bandwidth: 300MHz
- ♦ Low On-Capacitance: 19.5pF
- ♦ 0.036% Total Harmonic Distortion
- ♦ Low Supply Current: 1nA
- ♦ +1.8V to +5.5V Single-Supply Operation

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX4729EXT-T	-40°C to +85°C	6 SC70-6	ABU
MAX4729ELT-T*	-40°C to +85°C	6 μDFN-6	_
MAX4730EXT-T	-40°C to +85°C	6 SC70-6	ABV
MAX4730ELT-T*	-40°C to +85°C	6 µDFN-6	_

^{*}Future product—contact factory for availability.

Pin Configurations/Functional Diagrams/Truth Table



MIXIM

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

(All voltages referenced to ground)	
V+, IN0.3V	to +6V
COM, NO, NC (Note 1)0.3V to (V+	+0.3V)
Continuous Current (IN, V+, GND)	±30mA
Continuous Current (COM, NO, NC)	±80mA
Peak Current COM, NO, NC	
(Pulsed at 1ms, 10% Duty Cycle)±	150mA

168mW
245mW
40°C to +85°C
+150°C
5°C to +150°C
+300°C

Note 1: Signals on NO, NC, or COM exceeding V+ or GND are clamped by internal diodes. Signals on IN exceeding GND are clamped by an internal diode. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V + = +2.7V \text{ to } +3.6V, V_{IH} = +2.0V, V_{IL} = +0.4V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}\text{C.}$) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
On-Resistance (Note 6)	Ron	V+ = 2.7V, I _{COM} = 10mA, V _{NO} or V _{NC} = 0V to V+	+25°C		3.5	5.5	Ω
On-Hesistance (Note o)	HON		T _{MIN} to T _{MAX}			5.7	
		$V+ = 2.7V$, $I_{COM} = 10mA$, V_{NO} or $V_{NC} = 0.7V$, 1.2V,	+25°C		0.05	0.15	Ω
On-Resistance Match Between	ΔRON	2V (MAX4729)	T _{MIN} to T _{MAX}			0.2	
Channels (Notes 3, 6)	AHON	V+ = 2.7V, I _{COM} = 10mA, V _{NO} or V _{NC} = 0.7V, 1.2V, 2V (MAX4730)	+25°C		0.2	0.34	
			T _{MIN} to T _{MAX}			0.37	
		$V + = 2.7V$, $I_{COM} = 10mA$,	+25°C		0.8	1.5	.2 95
On-Resistance Flatness (Note 4)	RFLAT(ON)	V_{NO} or $V_{NC} = 0.7V$, 1.2V, 2V (MAX4729)	T _{MIN} to T _{MAX}			2.2	
	TIFLAT(ON)	V+ = 2.7V, I _{COM} = 10mA, V _{NO} or V _{NC} = 0.7V, 1.2V, 2V (MAX4730)	+25°C		0.45	0.95	
			T _{MIN} to T _{MAX}			1.3	
NO NO Off Landau Comment	INO (OFF), INC (OFF)	V+ = 3.3V, V _{COM} = 1V, 3V, V _{NO} or V _{NC} = 3V, 1V	+25°C	-2	+0.01	+2	nA
NO, NC Off-Leakage Current			T _{MIN} to T _{MAX}	-3		+3	II/A
COM On-Leakage Current	loov (ov)	$V+=3.3V$, $V_{COM}=1V$ or $3V$, V_{NO} or $V_{NC}=1V$, $3V$, or float	+25°C	-3	+0.01	+3	- nA
	ICOM (ON)		T _{MIN} to T _{MAX}	-4		+4	
DIGITAL INPUTS	•						•
Input Logic High	VIH		T _{MIN} to T _{MAX}	2.0			V
Input Logic Low	V _{IL}		T _{MIN} to T _{MAX}		<u>-</u>	0.4	V
Input Leakage Current	I _{IN}	V _{IN} = 0V or 3.6V	T _{MIN} to T _{MAX}	-1	+0.005	+1	μΑ

ELECTRICAL CHARACTERISTICS (continued)

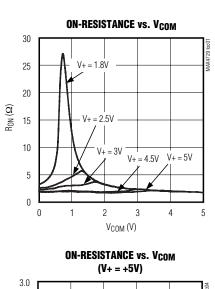
 $(V+ = +2.7V \text{ to } +3.6V, V_{IH} = +2.0V, V_{IL} = +0.4V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C.$) (Note 2)

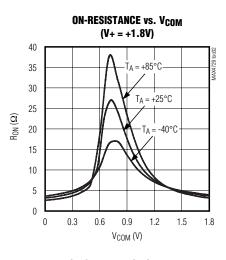
PARAMETER	SYMBOL	CONDITIONS T _A		MIN	TYP	MAX	UNITS	
DYNAMIC								
Turn-On Time (Note 5)	ton	$V_{NO}, V_{NC} = 2V, R_L = 300\Omega,$	+25°C		18	45	no	
Turn-Off Time (Note 3)	ίΟΝ	C _L = 35pF, Figure 1	T _{MIN} to T _{MAX}			45 ns		
Turn-Off Time (Note 5)	toff	V_{NO} , $V_{NC} = 2V$, $R_L = 300\Omega$,	+25°C		10	26 ns		
Turn on Time (Note 9)	OFF	C _L = 35pF, Figure 1	T _{MIN} to T _{MAX}			26	110	
Break-Before-Make (Note 5)		V_{NO} , $V_{NC} = 2V$, $R_L = 300\Omega$,	+25°C		5		ns	
Break Berere Make (Note 6)		C _L = 35pF, Figure 1	T _{MIN} to T _{MAX}	1				
Charge Injection	Q	$V_{GEN} = 0V$, $R_{GEN} = 0$, $C_L = -$	1.0nF, Figure 3		3		рС	
NO, NC Off-Capacitance	C _{NO} (OFF), C _{NC} (OFF)	f = 1MHz, Figure 4		6.5		рF		
Switch On-Capacitance	Con	f = 1MHz, Figure 4			19.5		рF	
Off-Isolation (Note 7)	Vice	V _{NO} = V _{NC} = 1V _{RMS} , R _L =	f = 1MHz		-67		dB	
On-isolation (Note 1)	V _{ISO}	50Ω , $C_L = 5pF$, Figure 2 $f = 10MHz$ -4	-45		ub_			
On-Channel Bandwidth -3dB	BW	Signal = $0dBm$, 50Ω in and out, Figure 2			300		MHz	
Crosstalk (Note 8)	VCT	NO or NC = $1V_{RMS}$, $C_L = 5pF$, $R_L = 50\Omega$, Figure 2	f = 1MHz		-67		— dB	
Crossiaik (Note 8)	VCI		f = 10MHz		-52			
Total Harmonic Distortion	THD	$R_L = 600\Omega$, V_{NC} or $V_{NO} = 2V_{P-P}$, $f = 20Hz$ to $20kHz$ $+25^{\circ}C$			0.035		%	
POWER SUPPLY								
Power-Supply Range	V+			1.8		5.5	V	
Positive Supply Current	l+	$V+ = 5.5V, V_{IN} = 0V \text{ or } 5.5V$	+25°C		0.001		μΑ	
	1+	V T = 3.5 V, V \(\) = 0 V (01 3.5 V)	T _{MIN} to T _{MAX}			1	μΑ	

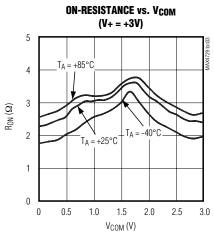
- Note 2: SC70 and μDFN parts are 100% tested at T_A = +25°C. Limits across the full-temperature range are guaranteed by design and correlation.
- **Note 3:** $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$.
- **Note 4:** R_{ON} flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.
- Note 5: Guaranteed by design.
- Note 6: µDFN is guaranteed by design.
- Note 7: Off-Isolation = 20log10 (VO / VI), where VO is V_{COM} and VI is either V_{NC} or V_{NO} from the network analyzer.
- Note 8: Crosstalk is measured between the two switches.

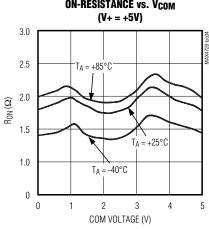
Typical Operating Characteristics

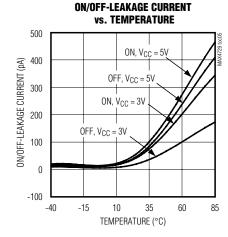
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

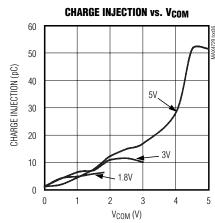


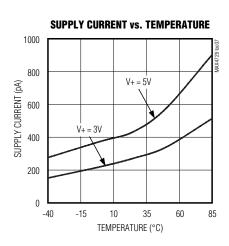


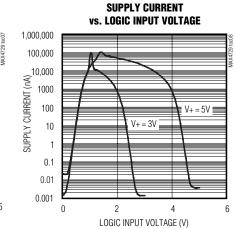


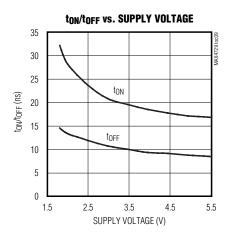






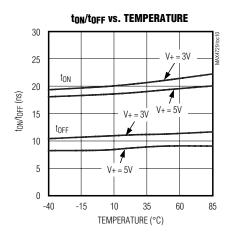


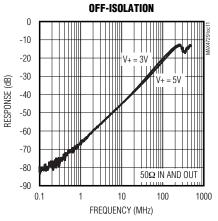


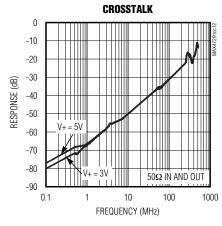


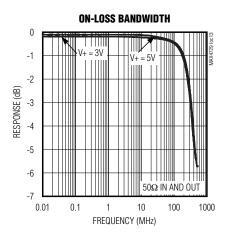
Typical Operating Characteristics (continued)

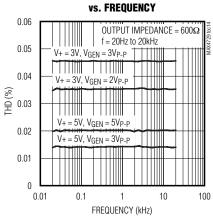
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



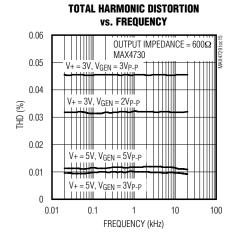








TOTAL HARMONIC DISTORTION



Pin Description

PIN				
MAX	4729	MAX4730	NAME	FUNCTION
SC70	μDFN	SC70/µDFN		
1	3	6	IN	Logic-Control Input
2	2	5	V+	Positive Supply Voltage
3	4	2	GND	Ground
4	6	3	NC	Analog Switch Normally Closed Terminal
5	5	4	COM	Analog Switch Common Terminal
6	1	1	NO	Analog Switch Normally Open Terminal

Detailed Description

The MAX4729/MAX4730 single-pole/double-throw (SPDT) switches operate from a single supply ranging from +1.8V to +5.5V. These switches provide low 3.5Ω on-resistance (RoN), as well as 0.45Ω RoN flatness with a 2.7V supply. These devices typically consume only 1nA of supply current, making them suitable for use in low-power, portable applications. The MAX4729/MAX4730 feature low-leakage currents over the entire temperature range, TTL/CMOS-compatible digital logic, and excellent AC characteristics.

Applications Information

Digital Control Inputs

The MAX4729/MAX4730 logic inputs accept up to +5.5V, regardless of supply voltage. For example, with a +3.3V

supply, IN can be driven low to GND and high to +5.5V, allowing for mixing of logic levels in a system. With a 2.7V to 3.6V power-supply voltage range, the logic thresholds are set so $V_{IL} = 0.4V$ (max) and $V_{IH} = 2V$ (min).

Power-Supply Sequencing and Overvoltage Protection

Caution: Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the device. Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+ before applying analog signals, especially if the analog signal is not current limited.

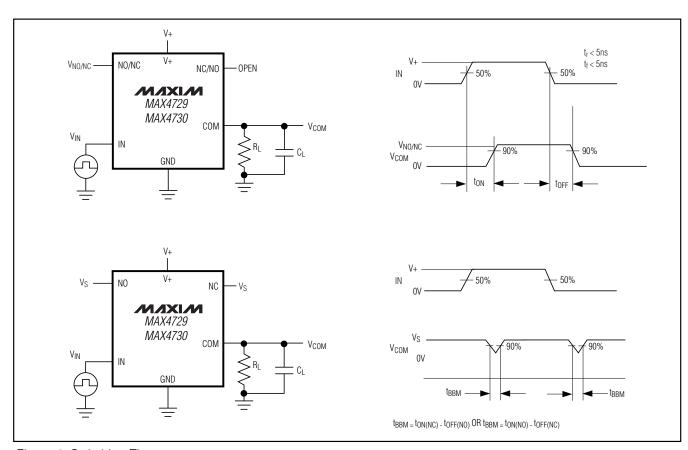


Figure 1. Switching Times

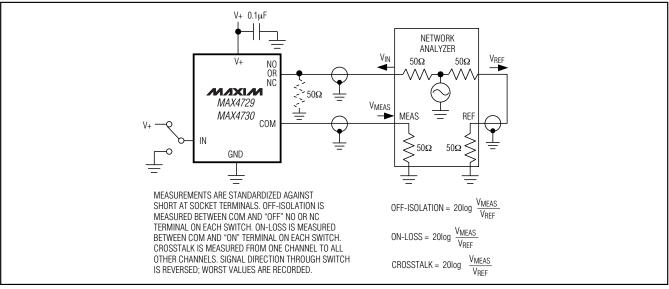


Figure 2. Off-Isolation/On-Loss Bandwidth, Crosstalk

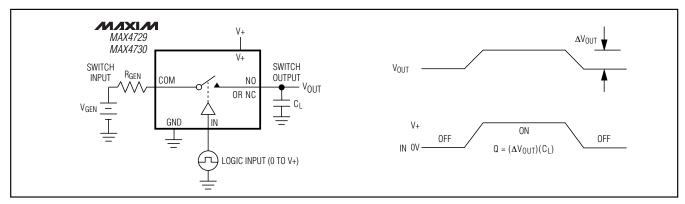


Figure 3. Charge Injection

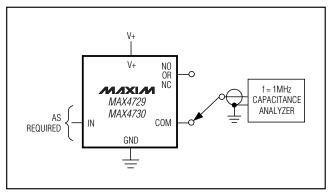


Figure 4. NO, NC, and COM Capacitance

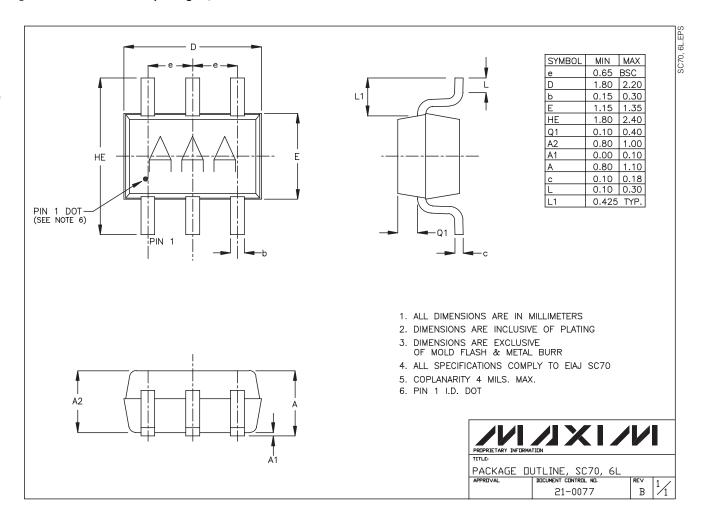
_Chip Information

TRANSISTOR COUNT: 190

PROCESS: CMOS

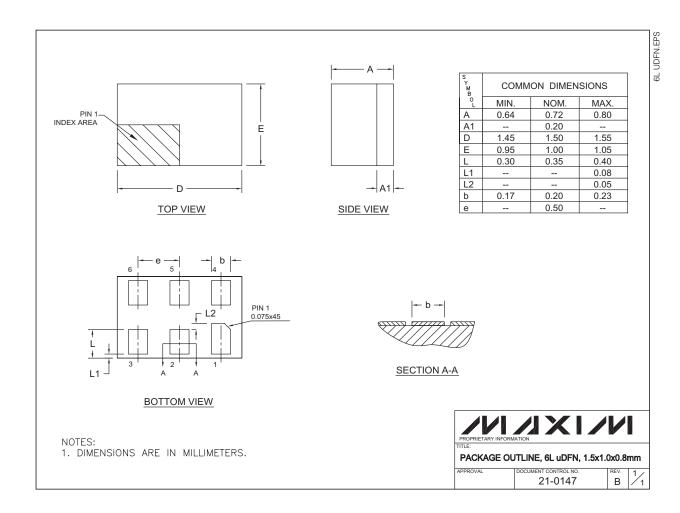
Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



Package Information (continued)

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